HALOGEN

FREE



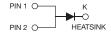
Vishay General Semiconductor

High Current Density Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier

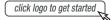
Ultra Low $V_F = 0.42 \text{ V}$ at $I_F = 5 \text{ A}$



SlimDPAK (TO-252AE)



DESIGN SUPPORT TOOLS





PRIMARY CHARACTERISTICS			
I _{F(AV)}	35 A		
V _{RRM}	120 V		
I _{FSM}	260 A		
V _F at I _F = 35 A (T _A = 125 °C)	0.68 V		
T _J max.	175 °C		
Package	SlimDPAK (TO-252AE)		
Circuit configuration	Single		

FEATURES

- Very low profile typical height of 1.3 mm
- Trench MOS Schottky technology
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage high frequency DC/DC converters, freewheeling diodes, and polarity protection applications.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V35PWM12	UNIT	
Device marking code		V35PWM12		
Maximum repetitive peak reverse voltage	V _{RRM}	120	V	
Maximum average forward rectified current (Fig. 1)	I _{F(AV)} (1)	35	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	260	А	
Operating junction temperature range	T _J ⁽²⁾	-40 to +175	°C	
Storage temperature range	T _{STG}	-55 to +175	°C	

Notes

⁽¹⁾ With infinite heatsink

 $^{^{(2)}}$ The heat generated must be less than the thermal conductivity from junction to ambient: $dP_D/dT_J < 1/R_{\theta JA}$



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum Instantaneous forward voltage	$I_F = 5.0 \text{ A}$	T _A = 25 °C	- V _F ⁽¹⁾	0.51	i	V
	$I_F = 17.5 A$			0.72	i	
	$I_F = 35 A$			0.96	1.05	
	$I_F = 5.0 \text{ A}$	T _A = 125 °C		0.42	i	
	$I_F = 17.5 A$			0.59	i	
	$I_F = 35 A$			0.68	0.76	
Reverse current	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	0.01	i	- mA
	v _R = 90 v	T _A = 125 °C		7	i	
	V _R = 120 V	T _A = 25 °C		-	1.2	ША
		T _A = 125 °C		13	40	
Typical junction capacitance	4.0 V, 1 MHz		CJ	2080	i	pF

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER SYMBOL V35PWM12 UN				
Tunical thormal registance	R ₀ JA (1)(2)	55	°C/W	
Typical thermal resistance	R _{0JM} (3)	1.5		

Notes

- $^{(1)}$ The heat generated must be less than thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
- $^{(2)}$ Free air, mounted on recommended copper pad area; thermal resistance $R_{\theta JA}$ junction to ambient
- $^{(3)}$ Mounted on infinite heat sink; thermal resistance $R_{\theta JM}$ junction-to-mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V35PWM12-M3/I	0.20	1	4500	13" diameter plastic tape and reel	
V35PWM12HM3/I (1)	0.20	I	4500	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

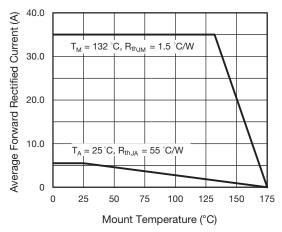


Fig. 1 - Maximum Forward Current Derating Curve

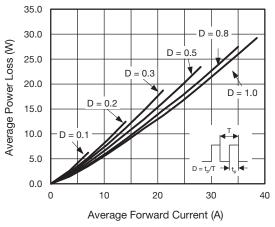


Fig. 2 - Forward Power Loss Characteristics

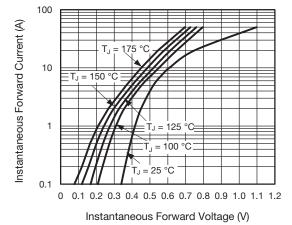


Fig. 3 - Typical Instantaneous Forward Characteristics

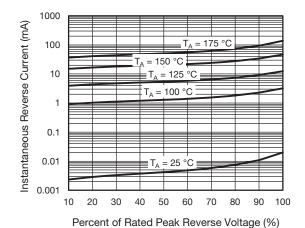


Fig. 4 - Typical Reverse Leakage Characteristics

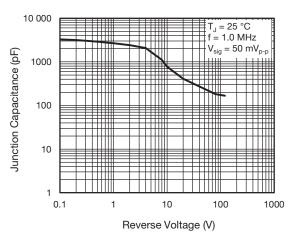


Fig. 5 - Typical Junction Capacitance

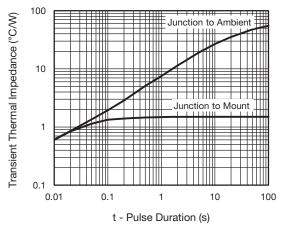


Fig. 6 - Typical Transient Thermal Impedance



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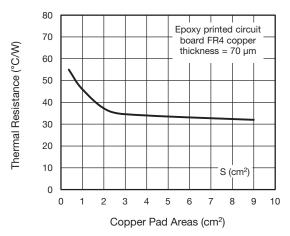
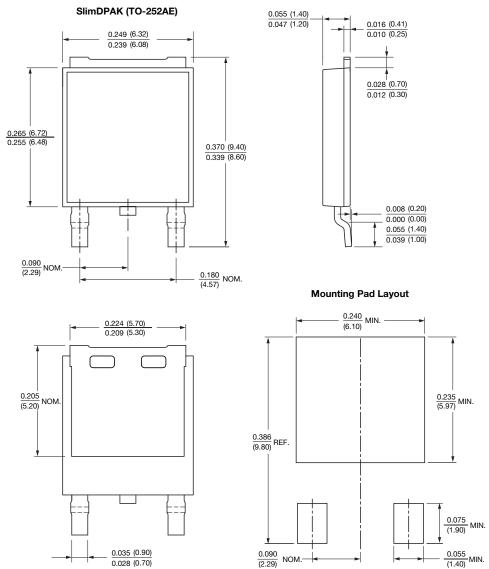


Fig. 7 - Typical Resistance Junction to Ambient vs. Copper Pad Areas

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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